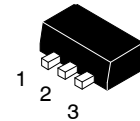


Bipolar Transistor

50 V, 2 A, Low $V_{CE(sat)}$, NPN Single

2SC5994



SOT-89 / PCP-1
CASE 419AU

Features

- Adoption of MBIT Process
- Low Collector to Emitter Saturation Voltage
- Large Current Capacity
- High Speed Switching

Applications

- Voltage Regulators
- Relay Drivers
- Lamp Drivers
- Electrical Equipment

SPECIFICATIONS

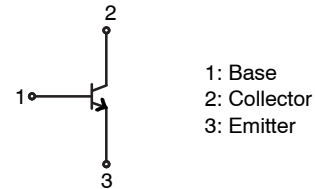
ABSOLUTE MAXIMUM RATINGS at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Value	Unit
Collector to Base Voltage	V_{CBO}	100	V
Collector to Emitter Voltage	V_{CES}	100	V
	V_{CEO}	50	V
Emitter to Base Voltage	V_{EBO}	6	V
Collector Current	I_C	2	A
Collector Current (Pulse)	I_{CP}	4	A
Base Current	I_B	400	mA
Collector Dissipation (Note 1) $T_C = 25^\circ\text{C}$	P_C	1.3	W
		3.5	
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 to +150	$^\circ\text{C}$

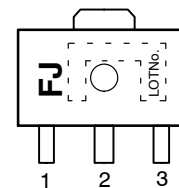
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface mounted on ceramic substrate (450 mm² x 0.8 mm).

ELECTRICAL CONNECTION



MARKING DIAGRAM



FJ = Specific Device Code

ORDERING INFORMATION

Device	Package	Shipping [†]
2SC5994-TD-E	SOT-89 / PCP-1	1000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

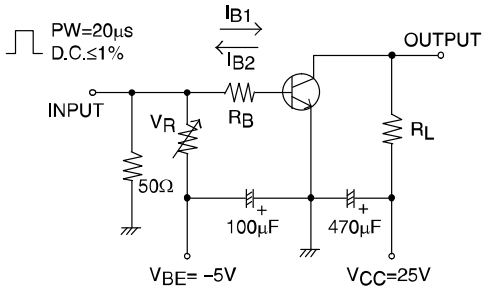
2SC5994

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = 50\text{ V}, I_E = 0\text{ A}$			1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 4\text{ V}, I_C = 0\text{ A}$			1	μA
DC Current Gain	h_{FE1}	$V_{CE} = 2\text{ V}, I_C = 100\text{ mA}$	200		560	
	h_{FE2}	$V_{CE} = 2\text{ V}, I_C = 1.5\text{ A}$	40			
Gain-Bandwidth Product	f_T	$V_{CE} = 10\text{ V}, I_C = 300\text{ mA}$		420		MHz
Output Capacitance	C_{ob}	$V_{CB} = 10\text{ V}, f = 1\text{ MHz}$		9		pF
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 1\text{ A}, I_B = 50\text{ mA}$		135	300	mV
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 1\text{ A}, I_B = 50\text{ mA}$		0.9	1.2	V
Collector to Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 10\text{ }\mu\text{A}, I_E = 0\text{ A}$	100			V
Collector to Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C = 100\text{ }\mu\text{A}, R_{BE} = 0\text{ }\Omega$	100			V
	$V_{(BR)CEO}$	$I_C = 1\text{ mA}, R_{BE} = \infty$	50			V
Emitter to Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10\text{ }\mu\text{A}, I_C = 0\text{ A}$	6			V
Turn-On Time	t_{on}	See specified Test Circuit		30		ns
Storage Time	t_{stg}			330		ns
Fall Time	t_f			40		ns

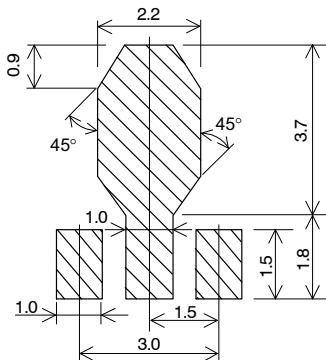
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit



$$I_C = 10\text{ mA}, I_{B1} = -10\text{ mA}, I_{B2} = 700\text{ mA}$$

Recommended Soldering Footprint



TYPICAL CHARACTERISTICS

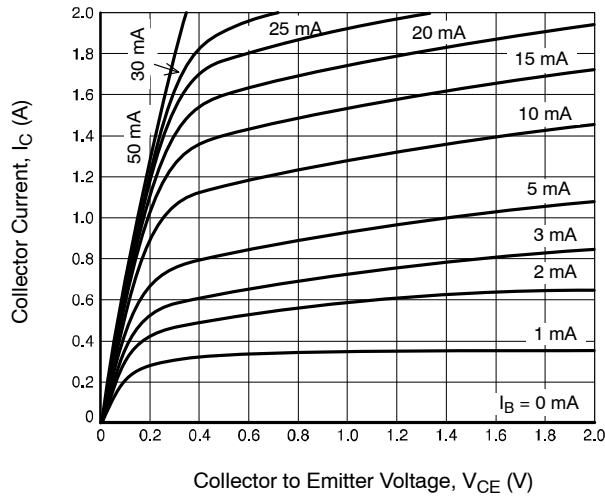


Figure 1. $I_C - V_{CE}$

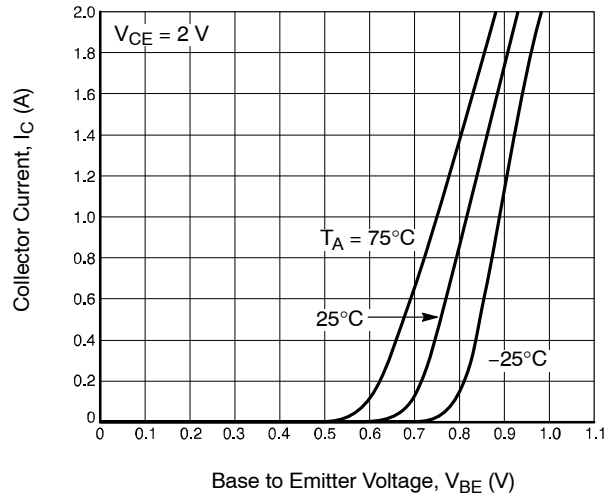


Figure 2. $I_C - V_{BE}$

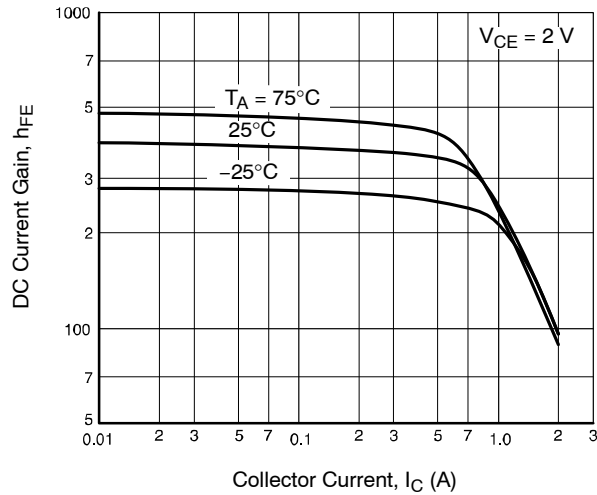


Figure 3. $h_{FE} - I_C$

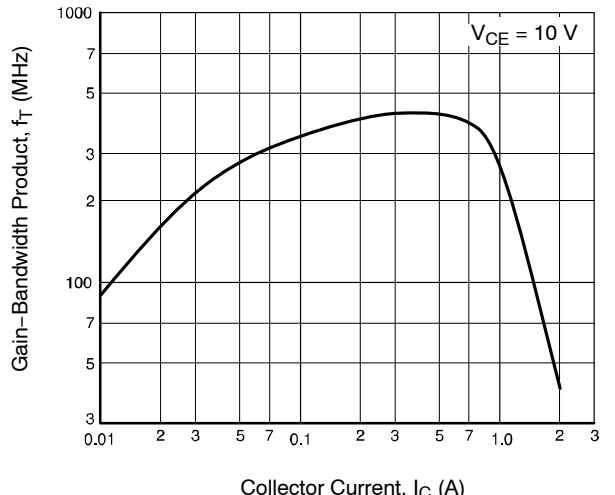


Figure 4. $f_T - I_C$

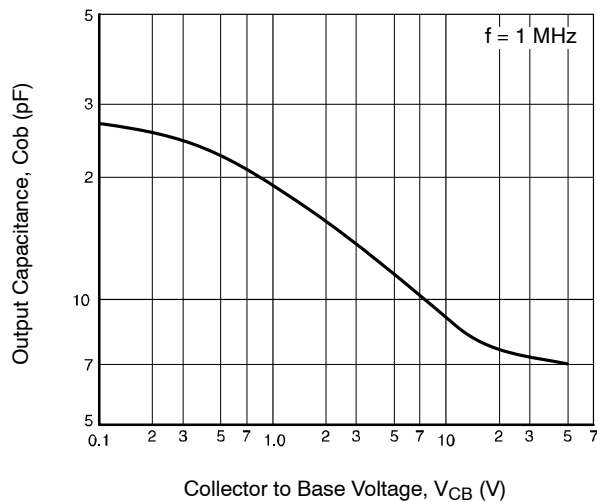


Figure 5. $C_{ob} - V_{CB}$

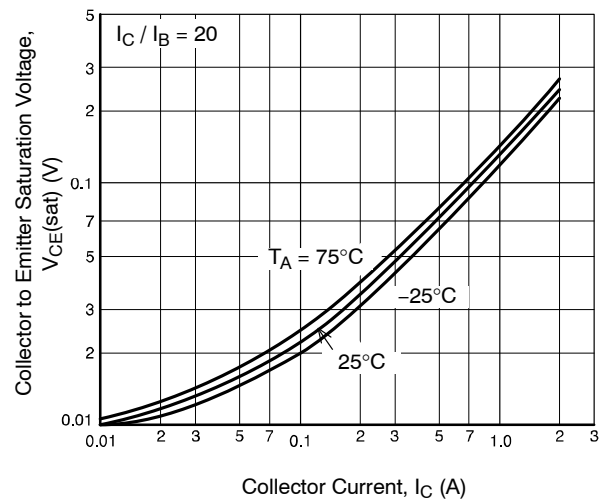


Figure 6. $V_{CE(sat)} - I_C$

TYPICAL CHARACTERISTICS (continued)

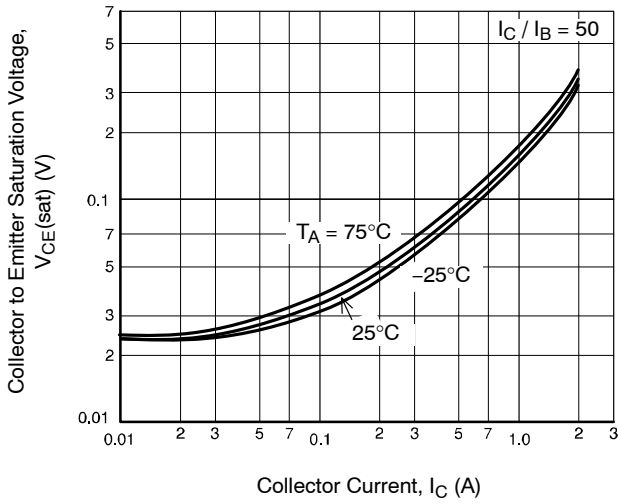


Figure 7. $V_{CE(sat)} - I_C$

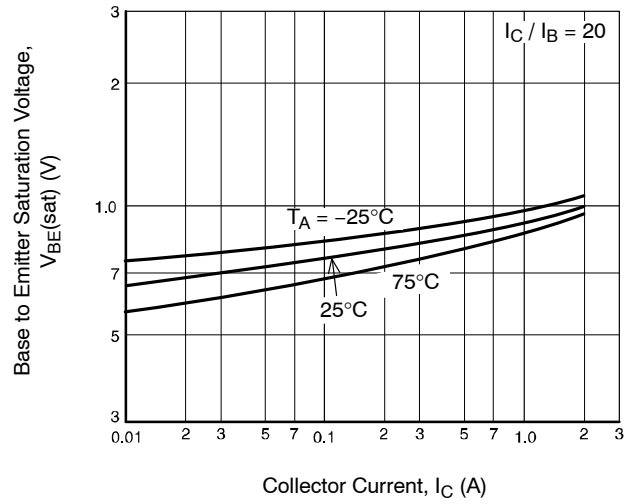


Figure 8. $V_{BE(sat)} - I_C$

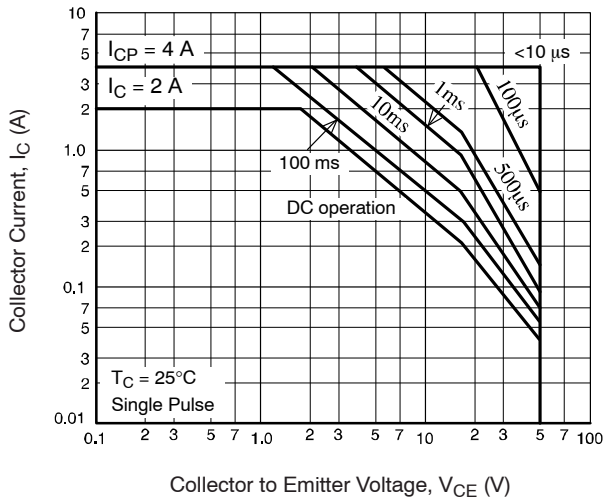


Figure 9. ASO

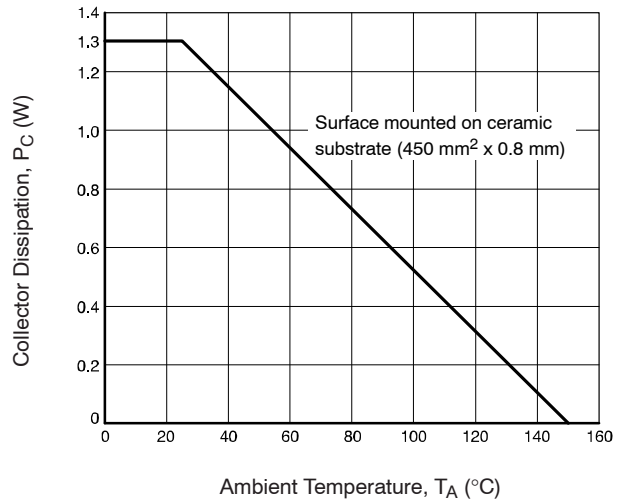


Figure 10. $P_C - T_A$

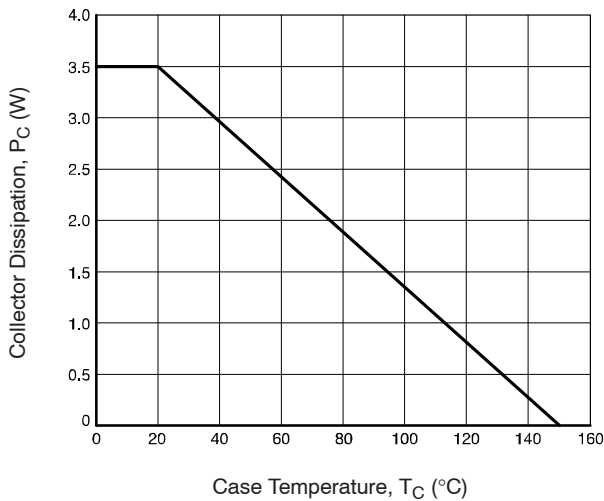
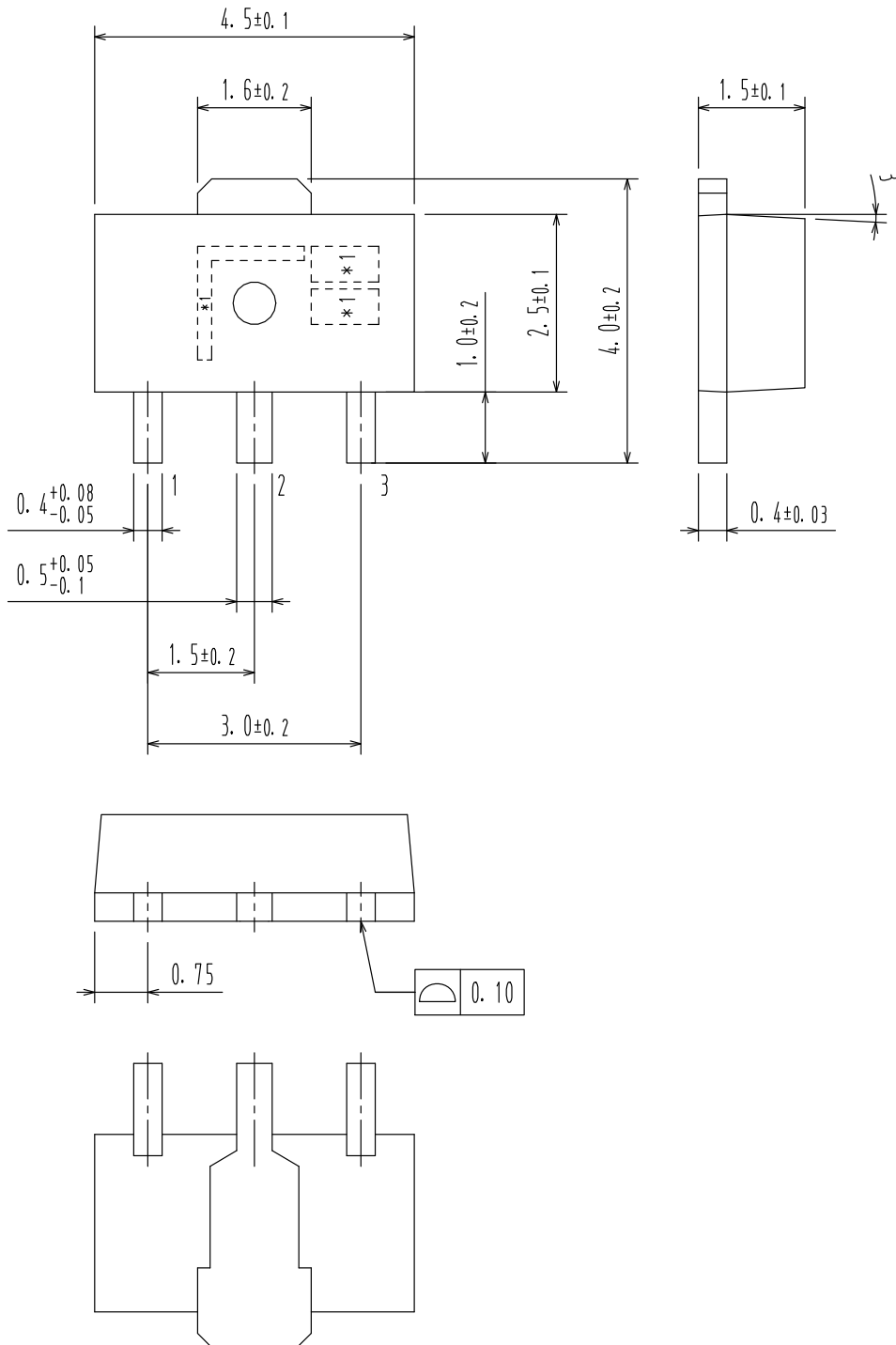


Figure 11. $P_C - T_C$


MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

SOT-89 / PCP-1
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ISSUE O

DATE 30 APR 2012



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